KVR1066D3E7K2/2G

2GB (1GB 128M x 72-Bit x 2 pcs.) PC3-8500
CL7 ECC 240-Pin DIMM Kit

DESCRIPTION:

ValueRAM's KVR1066D3E7K2/2G is a kit of two 128M x 72-bit 1GB (1024MB) DDR3-1066 CL7 SDRAM (Synchronous DRAM) ECC memory modules, based on eighteen 64M x 8-bit DDR3-1066 FBGA components per module. The SPDs are programmed to JEDEC standard latency 1066Mhz timing of 7-7-7 at 1.5V. Each 240-pin DIMM uses gold contact fingers and requires +1.5V. The electrical and mechanical specifications are as follows:

FEATURES:

- ☑ JEDEC standard 1.5V ± 0.075V Power Supply
- ☑ VDDQ = 1.5V ± 0.075V
- ☑ 533MHz fCK for 1066Mb/sec/pin
- ☑ 8 independent internal bank
- ☑ Programmable CAS Latency: 5,6,7,8,9,10
- ☑ Posted CAS
- ☑ Programmable Additive Latency: 0, CL - 2, or CL - 1 clock
- ☑ Programmable CAS Write Latency(CWL) = 7(DDR3-1066)
- ☑ 8-bit pre-fetch
- ☑ Burst Length: 8 (Interleave without any limit, sequential with starting address “000” only), 4 with tCCD = 4 which does not allow seamless read or write [either on the fly using A12 or MRS]
- ☑ Bi-directional Differential Data Strobe
- ☑ Internal(self) calibration : Internal self calibration through ZQ pin (RZQ : 240 ohm ± 1%)
- ☑ On Die Termination using ODT pin
- ☑ Average Refresh Period 7.8us at lower then TCASE 85°C, 3.9us at 85°C < TCASE . 95°C
- ☑ Asynchronous Reset
- ☑ 1066Mbps CL7 doesn’t have backward compatibility with 800Mbps CL5
- ☑ PCB : Height 1.180” (30.00mm), double sided component

PERFORMANCE:

☑ CL(IDD)	7 cycles
☑ Row Cycle Time (tRCmin)	50.63ns (min.)
☑ Refresh to Active/Refresh Command Time (tRFCmin)	90ns
☑ Row Active Time (tRASmin)	37.5ns (min.)
☑ Power	TBD W (operating per module)
☑ UL Rating	94 V - 0
☑ Operating Temperature	0° C to 85° C
☑ Storage Temperature	-55° C to +100° C

Preliminary

MODULE DIMENSIONS: